

RQ3E100MNTB1

RQ3E100MNTB1 Information

Winnelsener.com	RQ3E100MNTB1 Rohm Semiconductor Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 30V 10A HSMT8 8-PowerVDFN For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RQ3E100MNTB1 Specifications

Manufacturer Part Number	RQ3E100MNTB1
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerVDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	9.9nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	520pF @ 15V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	2W (Ta)
Rds On (Max) @ Id, Vgs	12.3 mOhm @ 10A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-HSMT (3.2x3)
Package / Case	8-PowerVDFN
	Report errors?

RQ3E100MNTB1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RQ3E100MNTB1 Payment Methods





If you have any question about RQ3E100MNTB1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com